

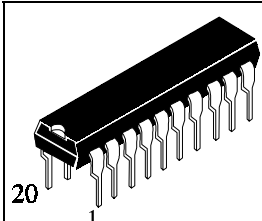
IN74ACT241

Octal 3-State Noninverting Buffer/Line Driver/Line Receiver
High-Speed Silicon-Gate CMOS

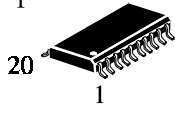
The IN74ACT241 is identical in pinout to the LS/ALS241, HC/HCT241. The IN74ACT241 may be used as a level converter for interfacing TTL or NMOS outputs to High Speed CMOS inputs.

This octal noninverting buffer/line driver/line receiver is designed to be used with 3-state memory address drivers, clock drivers, and other bus-oriented systems. The device has noninverting outputs and two output enables. Enable A is active-low and Enable B is active-high.

- TTL/NMOS Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 μ A; 0.1 μ A @ 25°C
- Outputs Source/Sink 24 mA



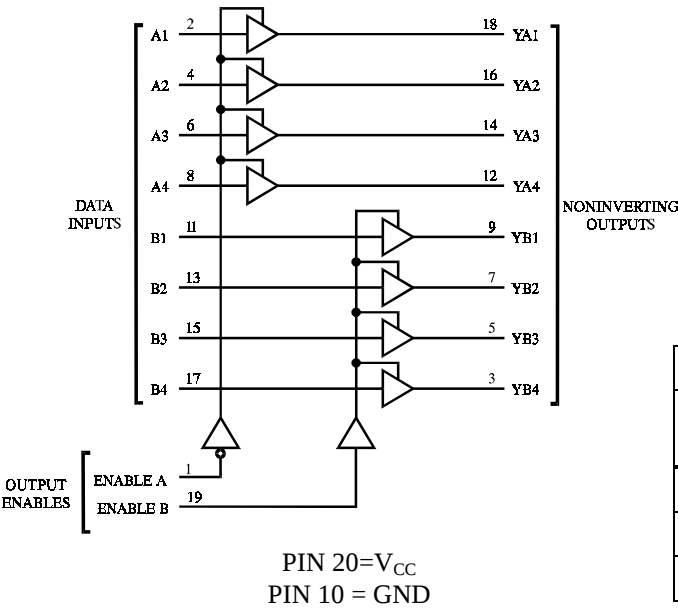
N SUFFIX
PLASTIC



DW SUFFIX
SOIC

ORDERING INFORMATION
IN74ACT241N Plastic
IN74ACT241DW SOIC
 $T_A = -40^{\circ}$ to 85° C for all packages

LOGIC DIAGRAM



PIN ASSIGNMENT

ENABLE A	1	20	V_{CC}
A1	2	19	ENABLE B
YB4	3	18	YA1
A2	4	17	B4
YB3	5	16	YA2
A3	6	15	B3
YB2	7	14	YA3
A4	8	13	B2
YB1	9	12	YA4
GND	10	11	B1

FUNCTION TABLE

Inputs		Output	Inputs		Output
Enable A	A	YA	Enable B	B	YB
L	L	L	H	L	L
L	H	H	H	H	H
H	X	Z	L	X	Z

X = don't care
Z = high impedance

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)	-0.5 to $V_{CC} + 0.5$	V
V_{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to $V_{CC} + 0.5$	V
I_{IN}	DC Input Current, per Pin	± 20	mA
I_{OUT}	DC Output Sink/Source Current, per Pin	± 50	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	± 50	mA
P_D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package: - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	4.5	5.5	V
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V_{CC}	V
T_J	Junction Temperature (PDIP)		140	°C
T_A	Operating Temperature, All Package Types	-40	+85	°C
I_{OH}	Output Current - High		-24	mA
I_{OL}	Output Current - Low		24	mA
t_r, t_f	Input Rise and Fall Time * (except Schmitt Inputs)	$V_{CC} = 4.5\text{ V}$ $V_{CC} = 5.5\text{ V}$	0 10 8.0	ns/V

* V_{IN} from 0.8 V to 2.0 V

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS(Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V _{CC} V	Guaranteed Limits		Unit
				25 °C	-40°C to 85°C	
V _{IH}	Minimum High-Level Input Voltage	V _{OUT} = V _{CC} -0.1 V	4.5 5.5	2.0 2.0	2.0 2.0	V
V _{IL}	Maximum Low - Level Input Voltage	V _{OUT} =0.1 V	4.5 5.5	0.8 0.8	0.8 0.8	V
V _{OH}	Minimum High-Level Output Voltage	I _{OUT} ≤ -50 µA	4.5 5.5	4.4 5.4	4.4 5.4	V
		*V _{IN} =V _{IH} I _{OH} =-24 mA	4.5 5.5	3.86 4.86	3.76 4.76	
		I _{OH} =-24 mA				
V _{OL}	Maximum Low-Level Output Voltage	I _{OUT} ≤ 50 µA	4.5 5.5	0.1 0.1	0.1 0.1	V
		*V _{IN} =V _{IL} I _{OL} =24 mA	4.5 5.5	0.36 0.36	0.44 0.44	
		I _{OL} =24 mA				
I _{IN}	Maximum Input Leakage Current	V _{IN} =V _{CC} or GND	5.5	±0.1	±1.0	µA
I _{OZ}	Maximum Three-State Leakage Current	V _{IN} (OE)=V _{IL} or V _{IH} V _{IN} =V _{CC} or GND V _{OUT} =V _{CC} or GND	5.5	±0.5	±5.0	µA
ΔI _{CCT}	Additional Max I _{CC} /Input	V _{IN} =V _{CC} - 2.1 V	5.5		1.5	mA
I _{OLD}	+Minimum Dynamic Output Current	V _{OLD} =1.65 V Max	5.5		75	mA
I _{OHD}	+Minimum Dynamic Output Current	V _{OHD} =3.85 V Min	5.5		-75	mA
I _{CC}	Maximum Quiescent Supply Current (per Package)	V _{IN} =V _{CC} or GND	5.5	8.0	80	µA

* All outputs loaded; thresholds on input associated with output under test.

+Maximum test duration 2.0 ms, one output loaded at a time.

AC ELECTRICAL CHARACTERISTICS($V_{CC}=5.0\text{ V} \pm 10\%$, $C_L=50\text{pF}$, Input $t_r=t_f=3.0\text{ ns}$)

Symbol	Parameter	Guaranteed Limits				Unit
		25 °C		-40°C to 85°C		
		Min	Max	Min	Max	
t _{PLH}	Propagation Delay, A to YA or B to YB (Figure 1)	1.5	9.0	1.5	10.0	ns
t _{PHL}	Propagation Delay, A to YA or B to YB (Figure 1)	1.5	9.0	1.5	10.0	ns
t _{PZH}	Propagation Delay, Output Enable to YA or YB (Figure 2)	1.5	9.0	1.0	10.0	ns
t _{PZL}	Propagation Delay, Output Enable to YA or YB (Figure 2)	1.5	10.0	1.5	11.0	ns
t _{PHZ}	Propagation Delay, Output Enable to YA or YB (Figure 2)	1.5	10.5	1.5	11.5	ns
t _{PLZ}	Propagation Delay, Output Enable to YA or YB (Figure 2)	2.0	10.5	1.5	11.5	ns
C _{IN}	Maximum Input Capacitance	4.5		4.5		pF
C _{PD}	Power Dissipation Capacitance	Typical @25°C, V _{CC} =5.0 V				pF
		45				

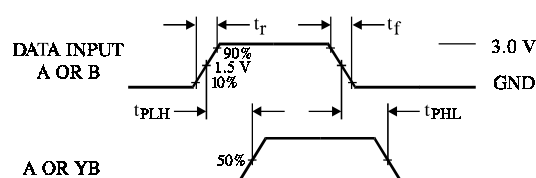


Figure 1. Switching Waveforms

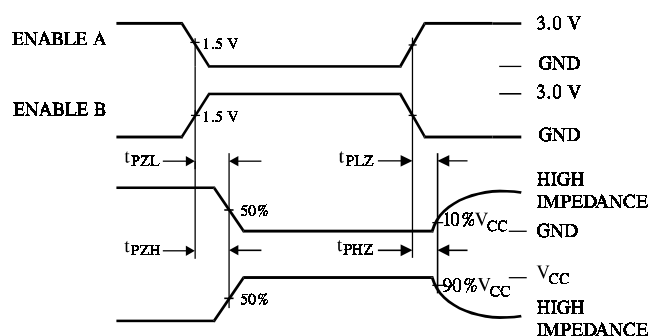


Figure 2. Switching Waveforms